



# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## General Description

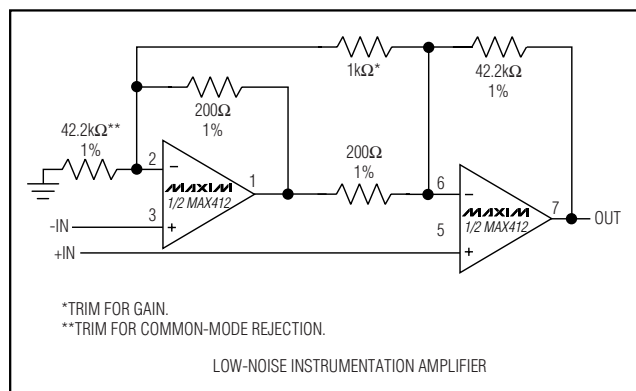
The MAX410/MAX412/MAX414 single/dual/quad op amps set a new standard for noise performance in high-speed, low-voltage systems. Input voltage-noise density is guaranteed to be less than  $2.4\text{nV}/\sqrt{\text{Hz}}$  at 1kHz. A unique design not only combines low noise with  $\pm 5\text{V}$  operation, but also consumes 2.5mA supply current per amplifier. Low-voltage operation is guaranteed with an output voltage swing of 7.3V<sub>p-p</sub> into 2k $\Omega$  from  $\pm 5\text{V}$  supplies. The MAX410/MAX412/MAX414 also operate from supply voltages between  $\pm 2.4\text{V}$  and  $\pm 5\text{V}$  for greater supply flexibility.

Unity-gain stability, 28MHz bandwidth, and 4.5V/ $\mu\text{s}$  slew rate ensure low-noise performance in a wide variety of wideband and measurement applications. The MAX410/MAX412/MAX414 are available in DIP and SO packages in the industry-standard single/dual/quad op amp pin configurations. The single comes in an ultra-small TDFN package (3mm x 3mm).

## Applications

Low-Noise Frequency Synthesizers  
Infrared Detectors  
High-Quality Audio Amplifiers  
Ultra Low-Noise Instrumentation Amplifiers  
Bridge Signal Conditioning

## Typical Operating Circuit



## Features

- ◆ Voltage Noise:  $2.4\text{nV}/\sqrt{\text{Hz}}$  (max) at 1kHz
- ◆ 2.5mA Supply Current Per Amplifier
- ◆ Low Supply Voltage Operation:  $\pm 2.4\text{V}$  to  $\pm 5\text{V}$
- ◆ 28MHz Unity-Gain Bandwidth
- ◆ 4.5V/ $\mu\text{s}$  Slew Rate
- ◆ 250 $\mu\text{V}$  (max) Offset Voltage (MAX410/MAX412)
- ◆ 115dB (min) Voltage Gain
- ◆ Available in an Ultra-Small TDFN Package

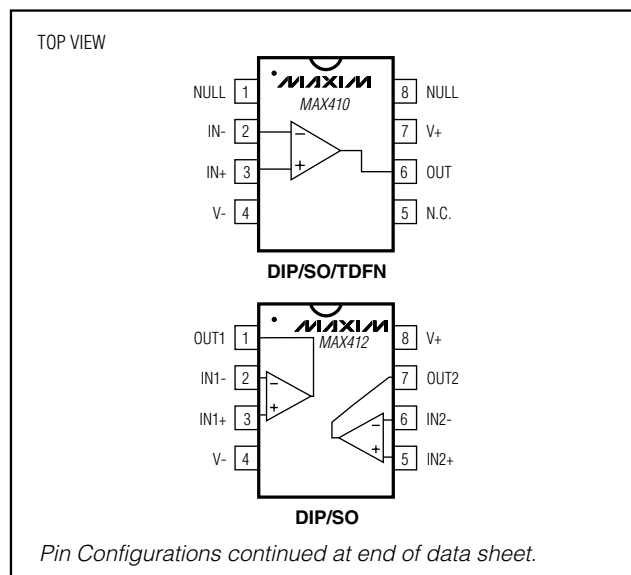
## Ordering Information

| PART       | TEMP RANGE     | PIN-PACKAGE   |
|------------|----------------|---------------|
| MAX410CPA  | 0°C to +70°C   | 8 Plastic DIP |
| MAX410BCPA | 0°C to +70°C   | 8 Plastic DIP |
| MAX410CSA  | 0°C to +70°C   | 8 SO          |
| MAX410BCSA | 0°C to +70°C   | 8 SO          |
| MAX410EPA  | -40°C to +85°C | 8 Plastic DIP |
| MAX410BEPA | -40°C to +85°C | 8 Plastic DIP |
| MAX410ESA  | -40°C to +85°C | 8 SO          |
| MAX410BESA | -40°C to +85°C | 8 SO          |
| MAX410ETA  | -40°C to +85°C | 8 TDFN-EP*    |

Ordering Information continued at end of data sheet.

\*EP—Exposed paddle. Top Mark—AGQ.

## Pin Configurations



# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## ABSOLUTE MAXIMUM RATINGS

Supply Voltage .....12V  
 Differential Input Current (Note 1) .....±20mA  
 Input Voltage Range.....V+ to V-  
 Common-Mode Input Voltage .....(V+ + 0.3V) to (V- - 0.3V)  
 Short-Circuit Current Duration.....Continuous  
 Continuous Power Dissipation (T<sub>A</sub> = +70°C)  
 MAX410/MAX412  
   8-Pin Plastic DIP (derate 9.09mW/°C above +70°C) ...727mW  
   8-Pin SO (derate 5.88mW/°C above +70°C).....471mW  
   8-Pin TDFN (derate 24.4mW/°C above +70°C) .....1951mW

### MAX414

14-Pin Plastic DIP (derate 10.00mW/°C above +70°C)800mW  
 14-Pin SO (derate 8.33mW/°C above +70°C).....667mW  
 Operating Temperature Ranges:  
   MAX41\_C\_ .....0°C to +70°C  
   MAX41\_E\_ .....-40°C to +85°C  
 Storage Temperature Range .....-65°C to +150°C  
 Lead Temperature (soldering, 10s) .....+300°C

**Note 1:** The amplifier inputs are connected by internal back-to-back clamp diodes. In order to minimize noise in the input stage, current-limiting resistors are not used. If differential input voltages exceeding ±1.0V are applied, limit input current to 20mA.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

## ELECTRICAL CHARACTERISTICS

(V+ = 5V, V- = -5V, T<sub>A</sub> = +25°C, unless otherwise noted.)

| PARAMETER                     | SYMBOL                | CONDITIONS                                    |                 | MIN          | TYP           | MAX  | UNITS  |
|-------------------------------|-----------------------|-----------------------------------------------|-----------------|--------------|---------------|------|--------|
| Input Offset Voltage          | V <sub>OS</sub>       | MAX410, MAX410B, MAX412, MAX412B              |                 |              | ±120          | ±250 | μV     |
|                               |                       | MAX414, MAX414B                               |                 |              | ±150          | ±320 |        |
| Input Bias Current            | I <sub>B</sub>        |                                               |                 |              | ±80           | ±150 | nA     |
| Input Offset Current          | I <sub>OS</sub>       |                                               |                 |              | ±40           | ±80  | nA     |
| Differential Input Resistance | R <sub>IN(Diff)</sub> |                                               |                 |              | 20            |      | kΩ     |
| Common-Mode Input Resistance  | R <sub>IN(CM)</sub>   |                                               |                 |              | 40            |      | MΩ     |
| Input Capacitance             | C <sub>IN</sub>       |                                               |                 |              | 4             |      | pF     |
| Input Noise-Voltage Density   | e <sub>n</sub>        | MAX410, MAX412, MAX414                        | 10Hz            |              | 7             |      | nV/√Hz |
|                               |                       |                                               | 1000Hz (Note 2) |              | 1.5           | 2.4  |        |
|                               |                       | MAX410B, MAX412B, MAX414B                     | 1000Hz (Note 2) |              | 2.4           | 4.0  |        |
| Input Noise-Current Density   | i <sub>n</sub>        | f <sub>O</sub> = 10Hz                         |                 |              | 2.6           |      | pA/√Hz |
|                               |                       | f <sub>O</sub> = 1000Hz                       |                 |              | 1.2           |      |        |
| Common-Mode Input Voltage     | V <sub>CM</sub>       |                                               |                 | ±3.5         | +3.7/<br>-3.8 |      | V      |
| Common-Mode Rejection Ratio   | CMRR                  | V <sub>CM</sub> = ±3.5V                       |                 | 115          | 130           |      | dB     |
| Power-Supply Rejection Ratio  | PSRR                  | V <sub>S</sub> = ±2.4V to ±5.25V              |                 | 96           | 103           |      | dB     |
| Large-Signal Gain             | A <sub>VOL</sub>      | R <sub>L</sub> = 2kΩ, V <sub>O</sub> = ±3.6V  |                 | 115          | 122           |      | dB     |
|                               |                       | R <sub>L</sub> = 600Ω, V <sub>O</sub> = ±3.5V |                 | 110          | 120           |      |        |
| Output Voltage Swing          | V <sub>OUT</sub>      | R <sub>L</sub> = 2kΩ                          |                 | +3.6<br>-3.7 | +3.7/<br>-3.8 |      | V      |
| Short-Circuit Output Current  | I <sub>SC</sub>       |                                               |                 |              | 35            |      | mA     |
| Slew Rate                     | SR                    | 10kΩ    20pF load                             |                 |              | 4.5           |      | V/μs   |
| Unity-Gain Bandwidth          | GBW                   | 10kΩ    20pF load                             |                 |              | 28            |      | MHz    |
| Settling Time                 | t <sub>S</sub>        | To 0.1%                                       |                 |              | 1.3           |      | μs     |
| Channel Separation            | C <sub>S</sub>        | f <sub>O</sub> = 1kHz                         |                 |              | 135           |      | dB     |

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

MAX410/MAX412/MAX414

## ELECTRICAL CHARACTERISTICS (continued)

(V<sub>+</sub> = 5V, V<sub>-</sub> = -5V, T<sub>A</sub> = +25°C, unless otherwise noted.)

| PARAMETER                      | SYMBOL         | CONDITIONS    | MIN  | TYP | MAX   | UNITS |
|--------------------------------|----------------|---------------|------|-----|-------|-------|
| Operating Supply-Voltage Range | V <sub>S</sub> |               | ±2.4 |     | ±5.25 | V     |
| Supply Current                 | I <sub>S</sub> | Per amplifier |      | 2.5 | 2.7   | mA    |

## ELECTRICAL CHARACTERISTICS

(V<sub>+</sub> = 5V, V<sub>-</sub> = -5V, T<sub>A</sub> = 0°C to +70°C, unless otherwise noted.)

| PARAMETER                    | SYMBOL               | CONDITIONS                                    | MIN  | TYP           | MAX  | UNITS |
|------------------------------|----------------------|-----------------------------------------------|------|---------------|------|-------|
| Input Offset Voltage         | V <sub>OS</sub>      |                                               |      | ±150          | ±350 | μV    |
| Offset Voltage Tempco        | ΔV <sub>OS</sub> /ΔT | Over operating temperature range              |      | ±1            |      | μV/°C |
| Input Bias Current           | I <sub>B</sub>       |                                               |      | ±100          | ±200 | nA    |
| Input Offset Current         | I <sub>OS</sub>      |                                               |      | ±80           | ±150 | nA    |
| Common-Mode Input Voltage    | V <sub>CM</sub>      |                                               | ±3.5 | +3.7/<br>-3.8 |      | V     |
| Common-Mode Rejection Ratio  | CMRR                 | V <sub>CM</sub> = ±3.5V                       | 105  | 121           |      | dB    |
| Power-Supply Rejection Ratio | PSRR                 | V <sub>S</sub> = ±2.4V to ±5.25V              | 90   | 97            |      | dB    |
| Large-Signal Gain            | A <sub>VOL</sub>     | R <sub>L</sub> = 2kΩ, V <sub>O</sub> = ±3.6V  | 110  | 120           |      | dB    |
|                              |                      | R <sub>L</sub> = 600Ω, V <sub>O</sub> = ±3.5V | 90   | 119           |      |       |
| Output Voltage Swing         | V <sub>OUT</sub>     | R <sub>L</sub> = 2kΩ                          | ±3.5 | +3.7/<br>-3.6 |      | V     |
| Supply Current               | I <sub>S</sub>       | Per amplifier                                 |      |               | 3.3  | mA    |

## ELECTRICAL CHARACTERISTICS

(V<sub>+</sub> = 5V, V<sub>-</sub> = -5V, T<sub>A</sub> = -40°C to +85°C, unless otherwise noted.) (Note 3)

| PARAMETER                    | SYMBOL               | CONDITIONS                                             | MIN  | TYP           | MAX  | UNITS |
|------------------------------|----------------------|--------------------------------------------------------|------|---------------|------|-------|
| Input Offset Voltage         | V <sub>OS</sub>      | MAX410, MAX410B, MAX412, MAX412B                       |      | ±200          | ±400 | μV    |
|                              |                      | MAX414, MAX414B                                        |      | ±200          | ±450 |       |
| Offset Voltage Tempco        | ΔV <sub>OS</sub> /ΔT | Over operating temperature range                       |      | ±1            |      | μV/°C |
| Input Bias Current           | I <sub>B</sub>       |                                                        |      | ±130          | ±350 | nA    |
| Input Offset Current         | I <sub>OS</sub>      |                                                        |      | ±100          | ±200 | nA    |
| Common-Mode Input Voltage    | V <sub>CM</sub>      |                                                        | ±3.5 | +3.7/<br>-3.6 |      | V     |
| Common-Mode Rejection Ratio  | CMRR                 | V <sub>CM</sub> = ±3.5V                                | 105  | 120           |      | dB    |
| Power-Supply Rejection Ratio | PSRR                 | V <sub>S</sub> = ±2.4V to ±5.25V                       | 90   | 94            |      | dB    |
| Large-Signal Gain            | A <sub>VOL</sub>     | R <sub>L</sub> = 2kΩ, V <sub>O</sub> = ±3.6V           | 110  | 118           |      | dB    |
|                              |                      | R <sub>L</sub> = 600Ω, V <sub>O</sub> = +3.4V to -3.5V | 90   | 114           |      |       |
| Output Voltage Swing         | V <sub>OUT</sub>     | R <sub>L</sub> = 2kΩ                                   | ±3.5 | +3.7/<br>-3.6 |      | V     |
| Supply Current               | I <sub>S</sub>       | Per amplifier                                          |      |               | 3.3  | mA    |

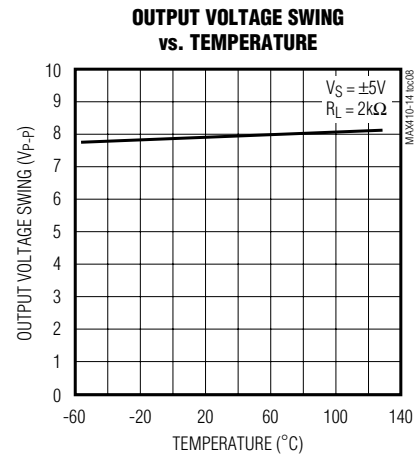
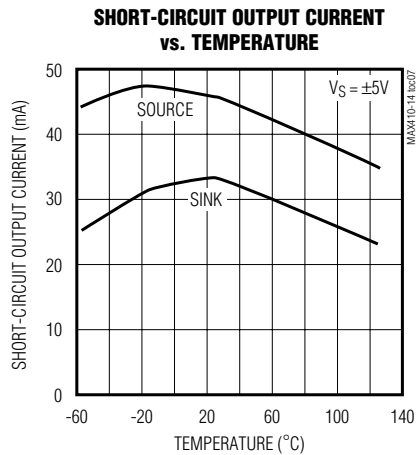
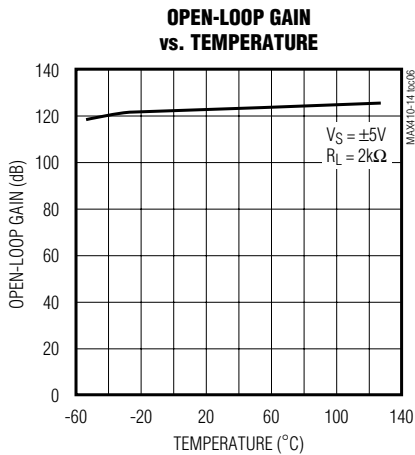
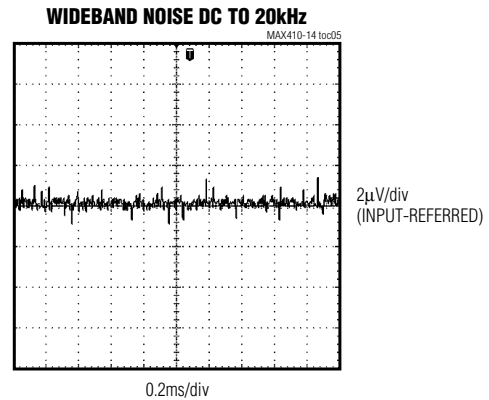
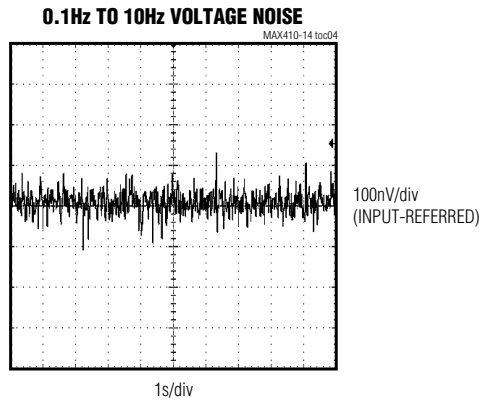
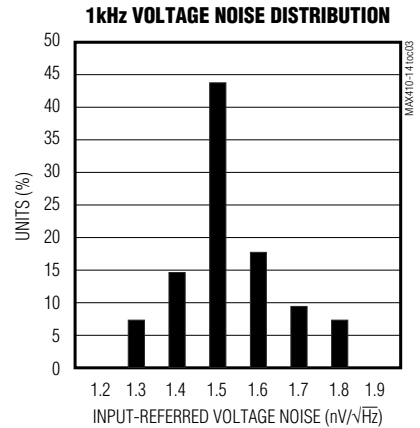
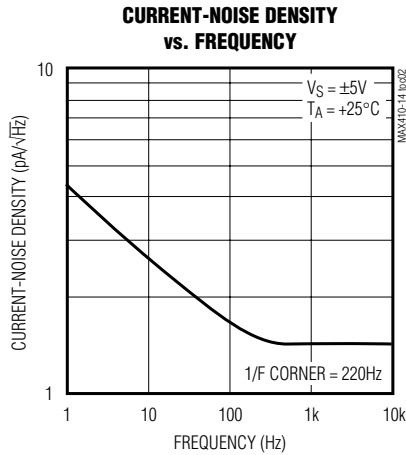
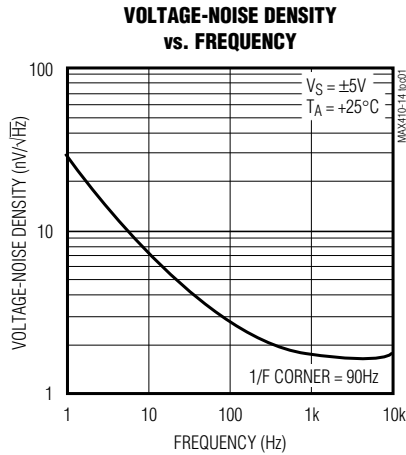
**Note 2:** Guaranteed by design.

**Note 3:** All TDFN devices are 100% tested at T<sub>A</sub> = +25°C. Limits over temperature for thin TDFNs are guaranteed by design.

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Typical Operating Characteristics

( $V_+ = 5V$ ,  $V_- = -5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

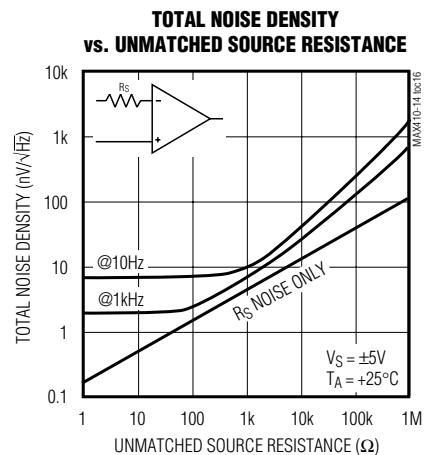
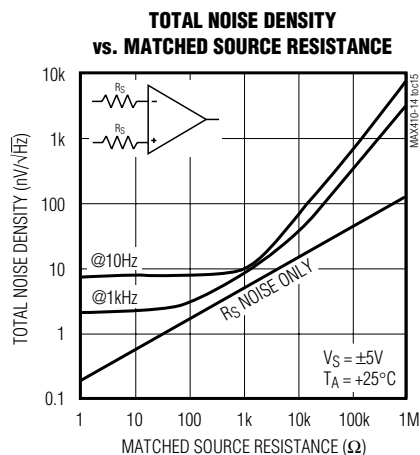
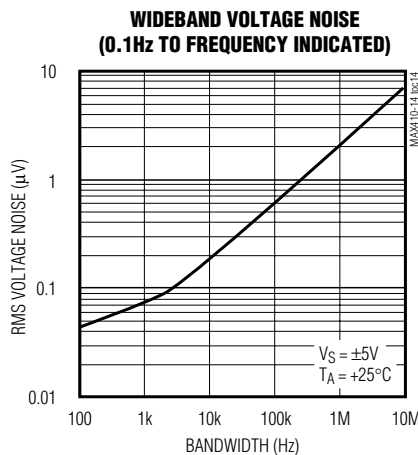
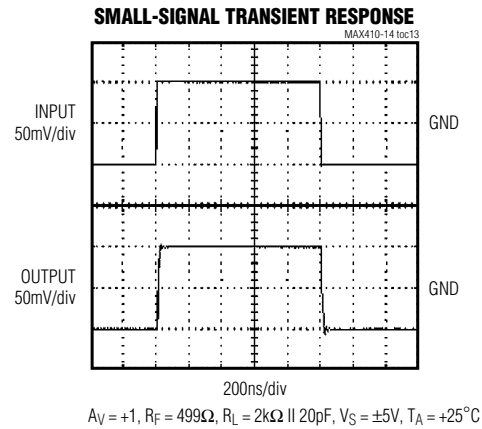
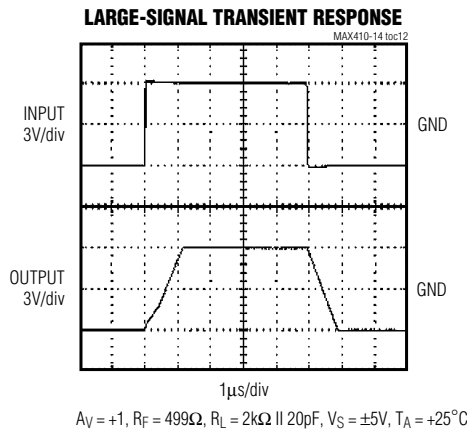
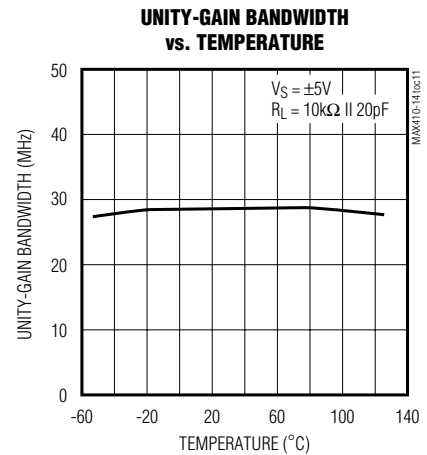
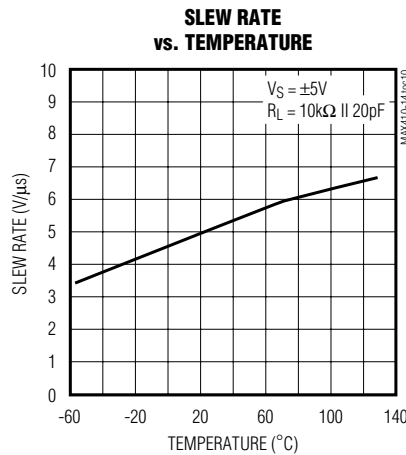
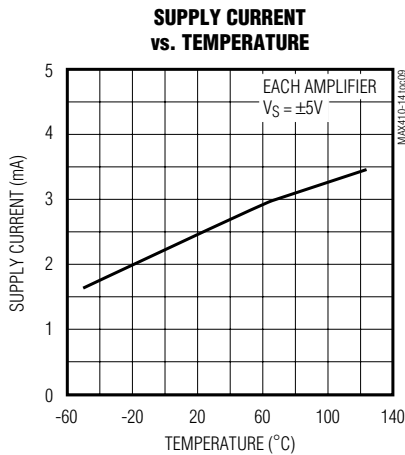


# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Typical Operating Characteristics (continued)

( $V_+ = 5V$ ,  $V_- = -5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

MAX410/MAX412/MAX414

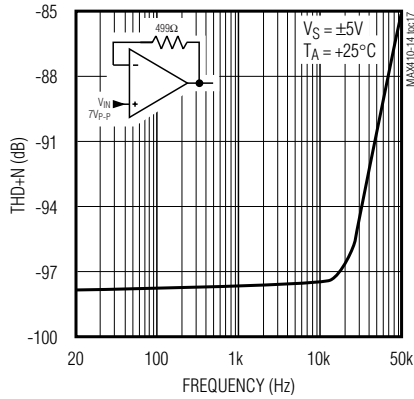


# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

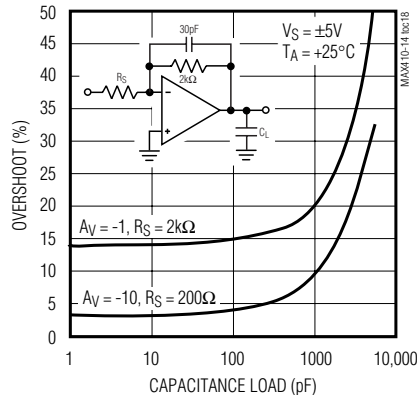
## Typical Operating Characteristics (continued)

( $V_+ = 5V$ ,  $V_- = -5V$ ,  $T_A = +25^\circ C$ , unless otherwise noted.)

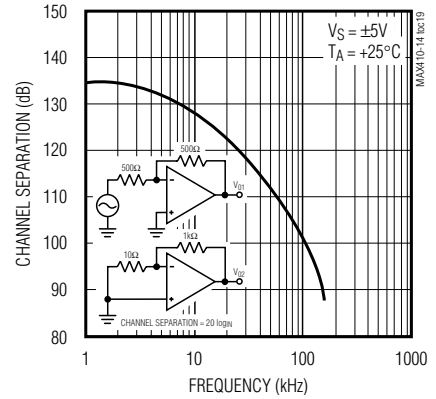
**TOTAL HARMONIC DISTORTION PLUS NOISE vs. FREQUENCY**



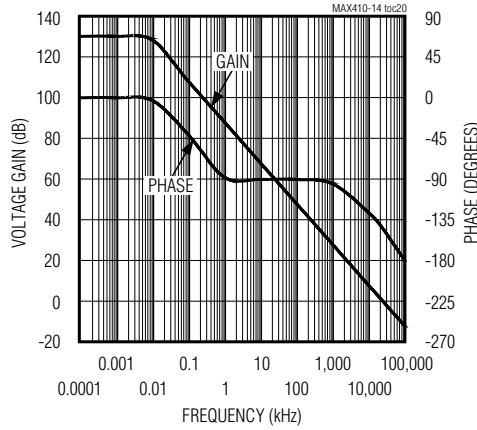
**PERCENTAGE OVERSHOOT vs. CAPACITIVE LOAD**



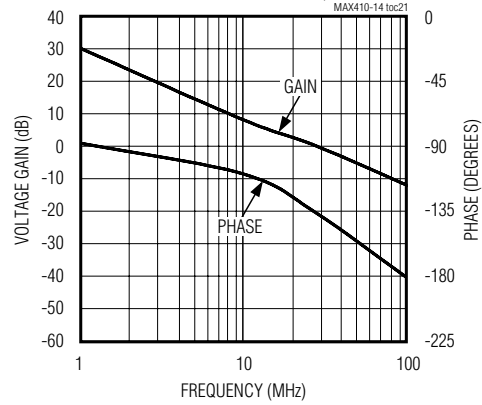
**MAX412/MAX414 CHANNEL SEPARATION vs. FREQUENCY**



**GAIN AND PHASE vs. FREQUENCY**



**GAIN AND PHASE vs. FREQUENCY**



# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Applications Information

The MAX410/MAX412/MAX414 provide low voltage-noise performance. Obtaining low voltage noise from a bipolar op amp requires high collector currents in the input stage, since voltage noise is inversely proportional to the square root of the input stage collector current. However, op amp current noise is proportional to the square root of the input stage collector current, and the input bias current is proportional to the input stage collector current. Therefore, to obtain optimum low-noise performance, DC accuracy, and AC stability, minimize the value of the feedback and source resistance.

### Total Noise Density vs. Source Resistance

The standard expression for the total input-referred noise of an op amp at a given frequency is:

$$e_t = \sqrt{e_n^2 + (R_p + R_n)^2 i_n^2 + 4kT(R_p + R_n)}$$

where:

$R_n$  = Inverting input effective series resistance

$R_p$  = Noninverting input effective series resistance

$e_n$  = Input voltage-noise density at the frequency of interest

$i_n$  = Input current-noise density at the frequency of interest

$T$  = Ambient temperature in Kelvin (K)

$k = 1.28 \times 10^{-23}$  J/K (Boltzman's constant)

In Figure 1,  $R_p = R_3$  and  $R_n = R_1 \parallel R_2$ . In a real application, the output resistance of the source driving the input must be included with  $R_p$  and  $R_n$ . The following example demonstrates how to calculate the total output-noise density at a frequency of 1kHz for the MAX412 circuit in Figure 1.

Gain = 1000

$4kT$  at  $+25^\circ\text{C} = 1.64 \times 10^{-20}$

$R_p = 100\Omega$

$R_n = 100\Omega \parallel 100k\Omega = 99.9\Omega$

$e_n = 1.5\text{nV}/\sqrt{\text{Hz}}$  at 1kHz

$i_n = 1.2\text{pA}/\sqrt{\text{Hz}}$  at 1kHz

$e_t = [(1.5 \times 10^{-9})^2 + (100 + 99.9)^2 (1.2 \times 10^{-12})^2 + (1.64 \times 10^{-20}) (100 + 99.9)]^{1/2} = 2.36\text{nV}/\sqrt{\text{Hz}}$  at 1kHz

Output noise density =  $(100)e_t = 2.36\mu\text{V}/\sqrt{\text{Hz}}$  at 1kHz.

In general, the amplifier's voltage noise dominates with equivalent source resistances less than  $200\Omega$ . As the equivalent source resistance increases, resistor noise

becomes the dominant term, eventually making the voltage noise contribution from the MAX410/MAX412/MAX414 negligible. As the source resistance is further increased, current noise becomes dominant. For example, when the equivalent source resistance is greater than  $3k\Omega$  at 1kHz, the current noise component is larger than the resistor noise. The graph of Total Noise Density vs. Matched Source Resistance in the *Typical Operating Characteristics* shows this phenomenon. Optimal MAX410/MAX412/MAX414 noise performance and minimal total noise achieved with an equivalent source resistance of less than  $10k\Omega$ .

### Voltage Noise Testing

RMS voltage-noise density is measured with the circuit shown in Figure 2, using the Quan Tech model 5173 noise analyzer, or equivalent. The voltage-noise density at 1kHz is sample tested on production units. When measuring op-amp voltage noise, only low-value, metal film resistors are used in the test fixture.

The 0.1Hz to 10Hz peak-to-peak noise of the MAX410/MAX412/MAX414 is measured using the test

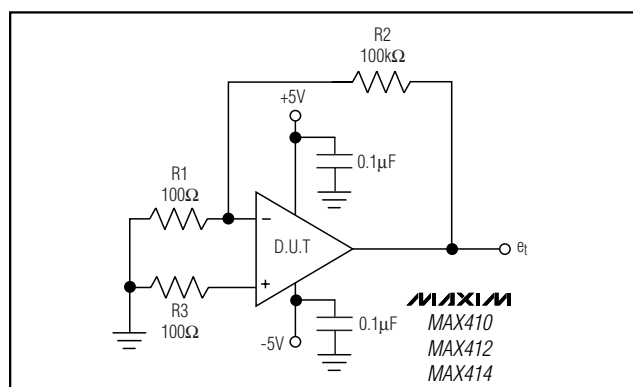


Figure 1. Total Noise vs. Source Resistance Example

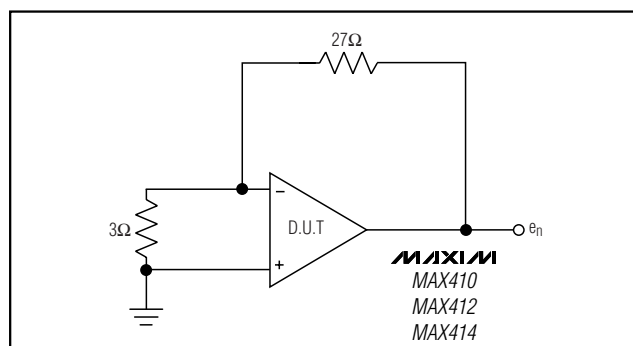


Figure 2. Voltage-Noise Density Test Circuit

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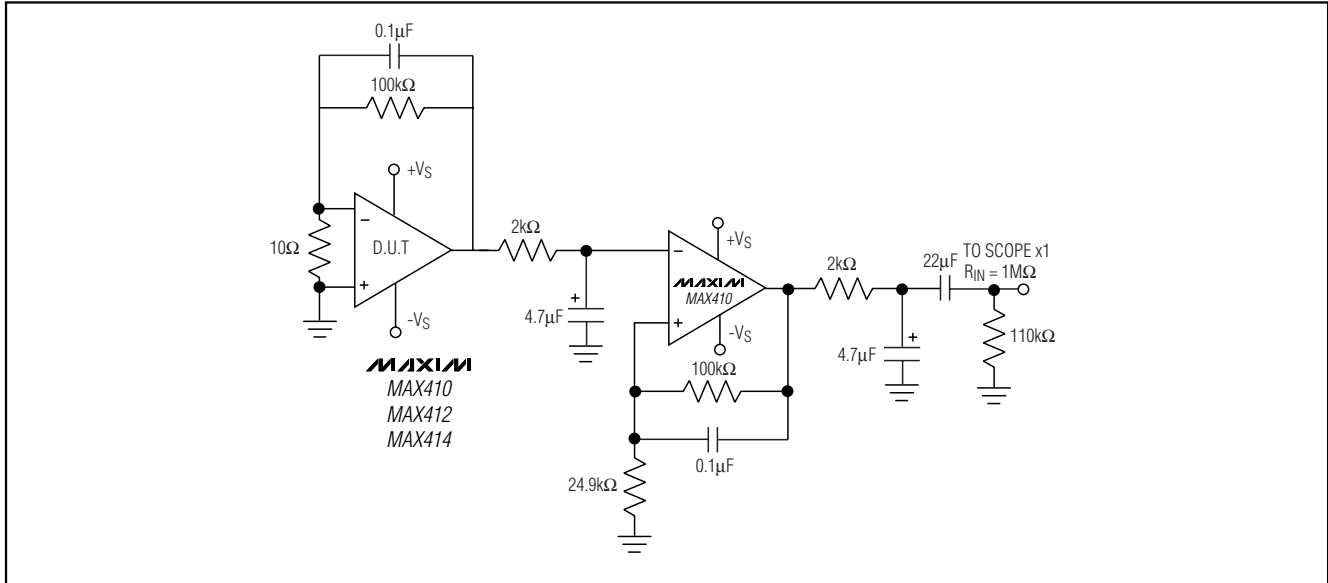


Figure 3. 0.1Hz to 10Hz Voltage Noise Test Circuit

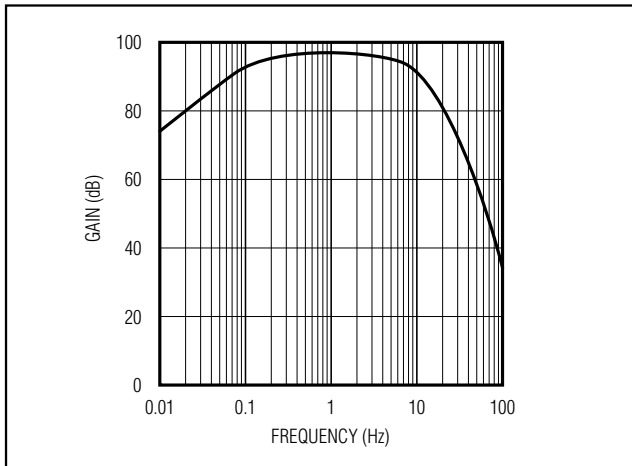


Figure 4. 0.1Hz to 10Hz Voltage Noise Test Circuit, Frequency Response

circuit shown in Figure 3. Figure 4 shows the frequency response of the circuit. The test time for the 0.1Hz to 10Hz noise measurement should be limited to 10 seconds, which has the effect of adding a second zero to the test circuit, providing increased attenuation for frequencies below 0.1Hz.

## Current Noise Testing

The current-noise density can be calculated, once the value of the input-referred noise is determined, by using the standard expression given below:

$$i_n = \frac{\sqrt{e_{no}^2 - [(A_{VCL})^2(4kT)(R_n + R_p)]}}{(R_n + R_p)(A_{VCL})} A/\sqrt{Hz}$$

where:

$R_n$  = Inverting input effective series resistance

$R_p$  = Noninverting input effective series resistance

$e_{no}$  = Output voltage-noise density at the frequency of interest ( $V/\sqrt{Hz}$ )

$i_n$  = Input current-noise density at the frequency of interest ( $A/\sqrt{Hz}$ )

$A_{VCL}$  = Closed-loop gain

$T$  = Ambient temperature in Kelvin (K)

$k = 1.38 \times 10^{-23}$  J/K (Boltzman's constant)

$R_p$  and  $R_n$  include the resistances of the input driving source(s), if any.

If the Quan Tech model 5173 is used, then the  $A_{VCL}$  terms in the numerator and denominator of the equation given above should be eliminated because the Quan



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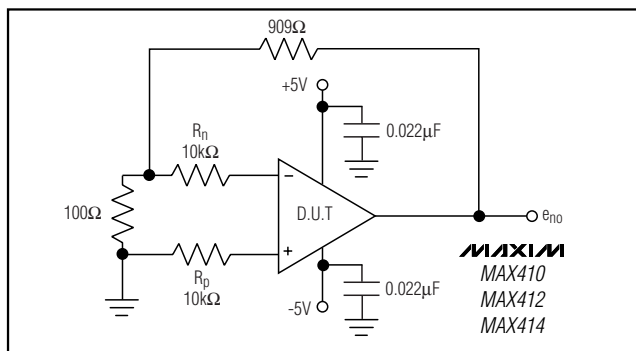


Figure 5. Current-Noise Test Circuit

Tech measures input-referred noise. For the circuit in Figure 5, assuming  $R_P$  is approximately equal to  $R_N$  and the measurement is taken with the Quan Tech model 5173, the equation simplifies to:

$$i_n = \frac{\sqrt{e_{no}^2 - [(1.64 \times 10^{-20})(20 \times 10^3)]}}{(20 \times 10^3)} \text{ A}/\sqrt{\text{Hz}}$$

## Input Protection

To protect amplifier inputs from excessive differential input voltages, most modern op amps contain input protection diodes and current-limiting resistors. These resistors increase the amplifier's input-referred noise. They have not been included in the MAX410/MAX412/MAX414, to optimize noise performance. The MAX410/MAX412/MAX414 do contain back-to-back input protection diodes which will protect the amplifier for differential input voltages of  $\pm 0.1V$ . If the amplifier must be protected from higher differential input voltages, add external current-limiting resistors in series with the op amp inputs to limit the potential input current to less than 20mA.

## Capacitive-Load Driving

Driving large capacitive loads increases the likelihood of oscillation in amplifier circuits. This is especially true for circuits with high loop gains, like voltage followers. The output impedance of the amplifier and a capacitive load form an RC network that adds a pole to the loop response. If the pole frequency is low enough, as when driving a large capacitive load, the circuit phase margin is degraded.

In voltage follower circuits, the MAX410/MAX412/MAX414 remain stable while driving capacitive loads as great as 3900pF (see Figures 6a and 6b).

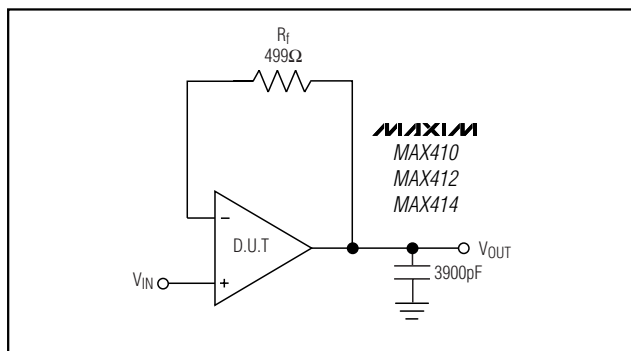


Figure 6a. Voltage Follower Circuit with 3900pF Load

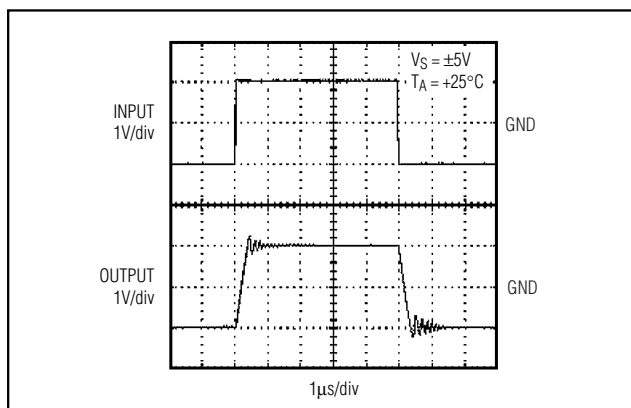


Figure 6b. Driving 3900pF Load as Shown in Figure 6a

When driving capacitive loads greater than 3900pF, add an output isolation resistor to the voltage follower circuit, as shown in Figure 7a. This resistor isolates the load capacitance from the amplifier output and restores the phase margin. Figure 7b is a photograph of the response of a MAX410/MAX412/MAX414 driving a 0.015μF load with a 10Ω isolation resistor

The capacitive-load driving performance of the MAX410/MAX412/MAX414 is plotted for closed-loop gains of -1V/V and -10V/V in the % Overshoot vs. Capacitive Load graph in the *Typical Operating Characteristics*.

Feedback around the isolation resistor  $R_I$  increases the accuracy at the capacitively loaded output (see Figure 8). The MAX410/MAX412/MAX414 are stable with a 0.01μF load for the values of  $R_I$  and  $C_F$  shown. In general, for decreased closed-loop gain, increase  $R_I$  or  $C_F$ . To drive larger capacitive loads, increase the value of  $C_F$ .

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

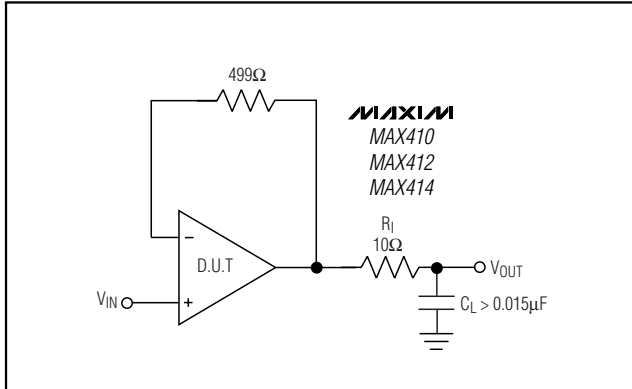


Figure 7a. Capacitive-Load Driving Circuit

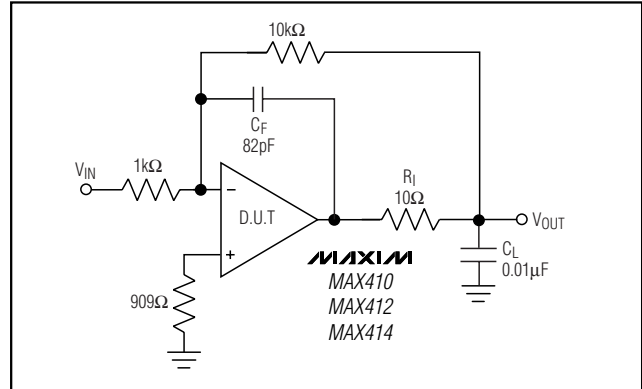


Figure 8. Capacitive-Load Driving Circuit with Loop-Enclosed Isolation Resistor

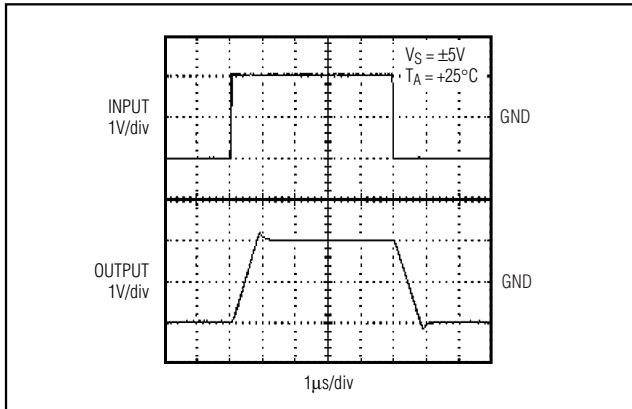


Figure 7b. Driving a 0.015μF Load with a 10Ω Isolation Resistor

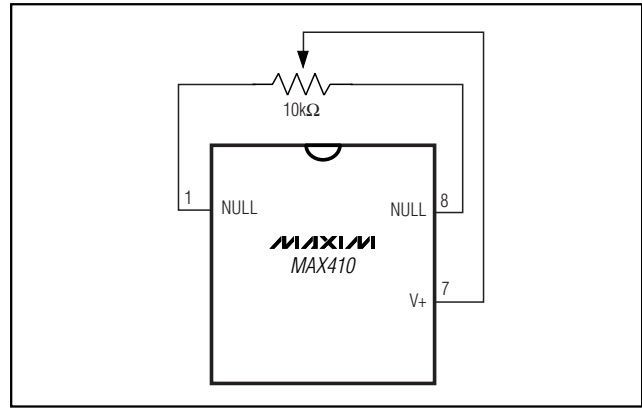


Figure 9. MAX410 Offset Null Circuit

## TDFN Exposed Paddle Connection

On TDFN packages, there is an exposed paddle that does not carry any current but should be connected to V- (not the GND plane) for rated power dissipation.

## Total Supply Voltage Considerations

Although the MAX410/MAX412/MAX414 are specified with ±5V power supplies, they are also capable of single-supply operation with voltages as low as 4.8V. The minimum input voltage range for normal amplifier operation is between V- + 1.5V and V+ - 1.5V. The minimum room-temperature output voltage range (with 2kΩ load)

is between V+ - 1.4V and V- + 1.3V for total supply voltages between 4.8V and 10V. The output voltage range, referenced to the supply voltages, decreases slightly over temperature, as indicated in the ±5V *Electrical Characteristics* tables. Operating characteristics at total supply voltages of less than 10V are guaranteed by design and PSRR tests.

## MAX410 Offset Voltage Null

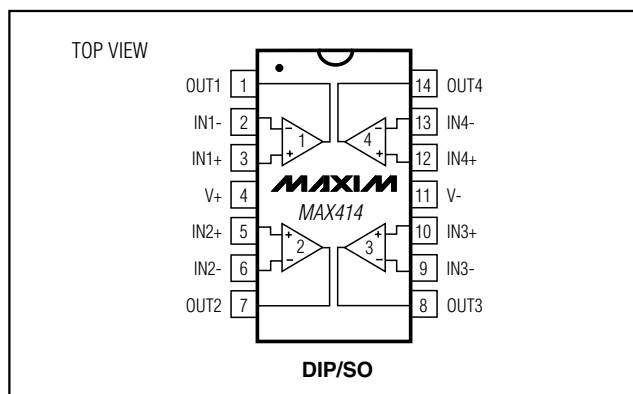
The offset null circuit of Figure 9 provides approximately ±450μV of offset adjustment range, sufficient for zeroing offset over the full operating temperature range,

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Ordering Information (continued)

| PART             | TEMP RANGE     | PIN-PACKAGE    |
|------------------|----------------|----------------|
| <b>MAX412CPA</b> | 0°C to +70°C   | 8 Plastic DIP  |
| MAX412BCPA       | 0°C to +70°C   | 8 Plastic DIP  |
| MAX412CSA        | 0°C to +70°C   | 8 SO           |
| MAX412BCSA       | 0°C to +70°C   | 8 SO           |
| MAX412EPA        | -40°C to +85°C | 8 Plastic DIP  |
| MAX412BEPA       | -40°C to +85°C | 8 Plastic DIP  |
| MAX412ESA        | -40°C to +85°C | 8 SO           |
| MAX412BESA       | -40°C to +85°C | 8 SO           |
| <b>MAX414CPD</b> | 0°C to +70°C   | 14 Plastic DIP |
| MAX414BCPD       | 0°C to +70°C   | 14 Plastic DIP |
| MAX414CSD        | 0°C to +70°C   | 14 SO          |
| MAX414BCSD       | 0°C to +70°C   | 14 SO          |
| MAX414EPD        | -40°C to +85°C | 14 Plastic DIP |
| MAX414BEPD       | -40°C to +85°C | 14 Plastic DIP |
| MAX414ESD        | -40°C to +85°C | 14 SO          |
| MAX414BESD       | -40°C to +85°C | 14 SO          |

## Pin Configurations (continued)



MAX410/MAX412/MAX414

## Chip Information

MAX410 TRANSISTOR COUNT: 132

MAX412 TRANSISTOR COUNT: 262

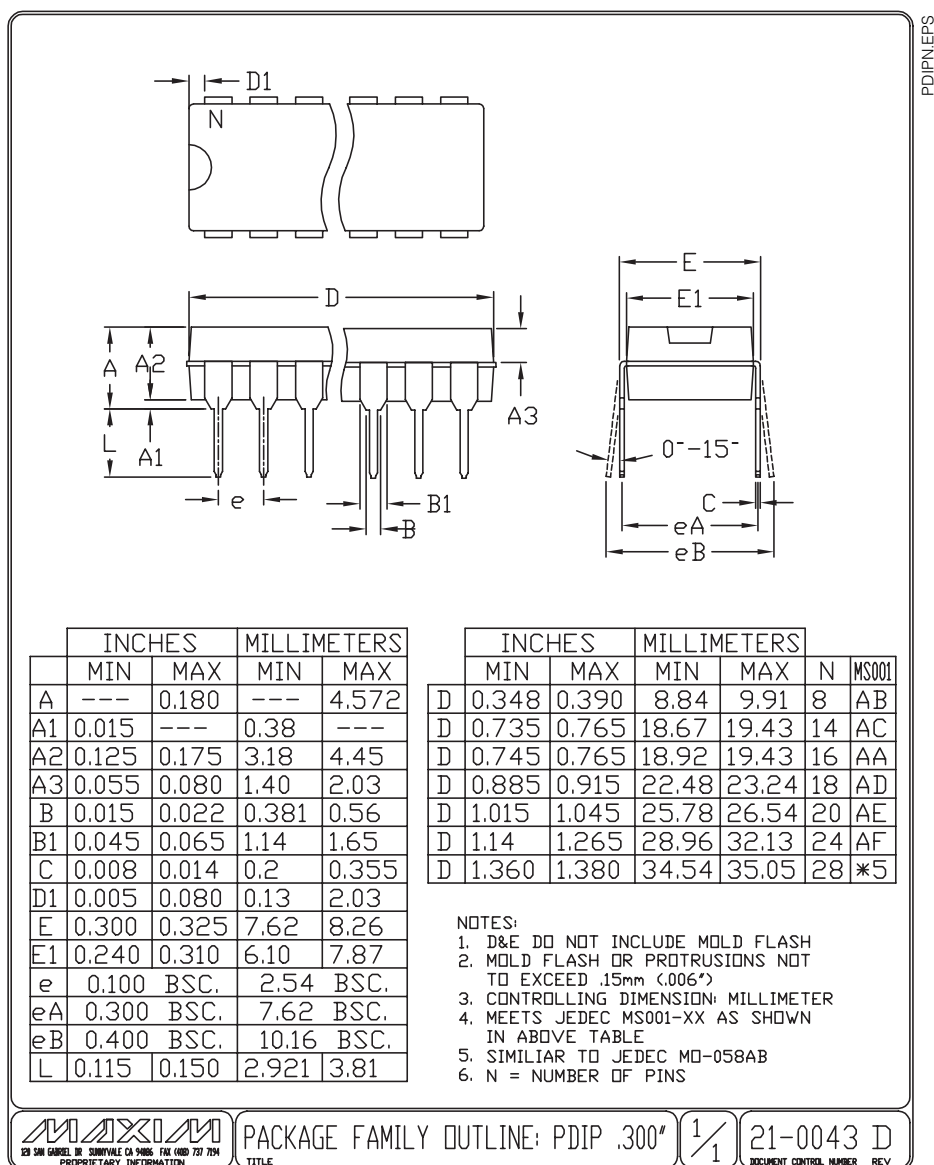
MAX414 TRANSISTOR COUNT: 2 × 262 (hybrid)

PROCESS: Bipolar

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)



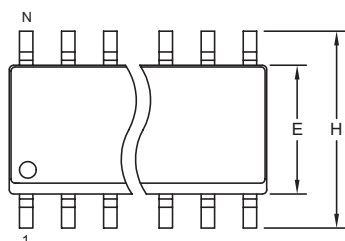
# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Package Information (continued)

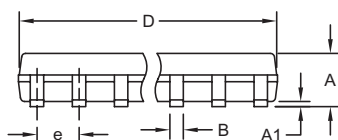
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)

MAX410/MAX412/MAX414

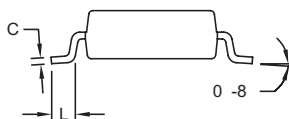
SOICN EPS



TOP VIEW



FRONT VIEW



SIDE VIEW

| DIM | INCHES    |       | MILLIMETERS |      |
|-----|-----------|-------|-------------|------|
|     | MIN       | MAX   | MIN         | MAX  |
| A   | 0.053     | 0.069 | 1.35        | 1.75 |
| A1  | 0.004     | 0.010 | 0.10        | 0.25 |
| B   | 0.014     | 0.019 | 0.35        | 0.49 |
| C   | 0.007     | 0.010 | 0.19        | 0.25 |
| e   | 0.050 BSC |       | 1.27 BSC    |      |
| E   | 0.150     | 0.157 | 3.80        | 4.00 |
| H   | 0.228     | 0.244 | 5.80        | 6.20 |
| L   | 0.016     | 0.050 | 0.40        | 1.27 |

### VARIATIONS:

| DIM | INCHES |       | MILLIMETERS |       | N  | MS012 |
|-----|--------|-------|-------------|-------|----|-------|
|     | MIN    | MAX   | MIN         | MAX   |    |       |
| D   | 0.189  | 0.197 | 4.80        | 5.00  | 8  | AA    |
| D   | 0.337  | 0.344 | 8.55        | 8.75  | 14 | AB    |
| D   | 0.386  | 0.394 | 9.80        | 10.00 | 16 | AC    |

### NOTES:

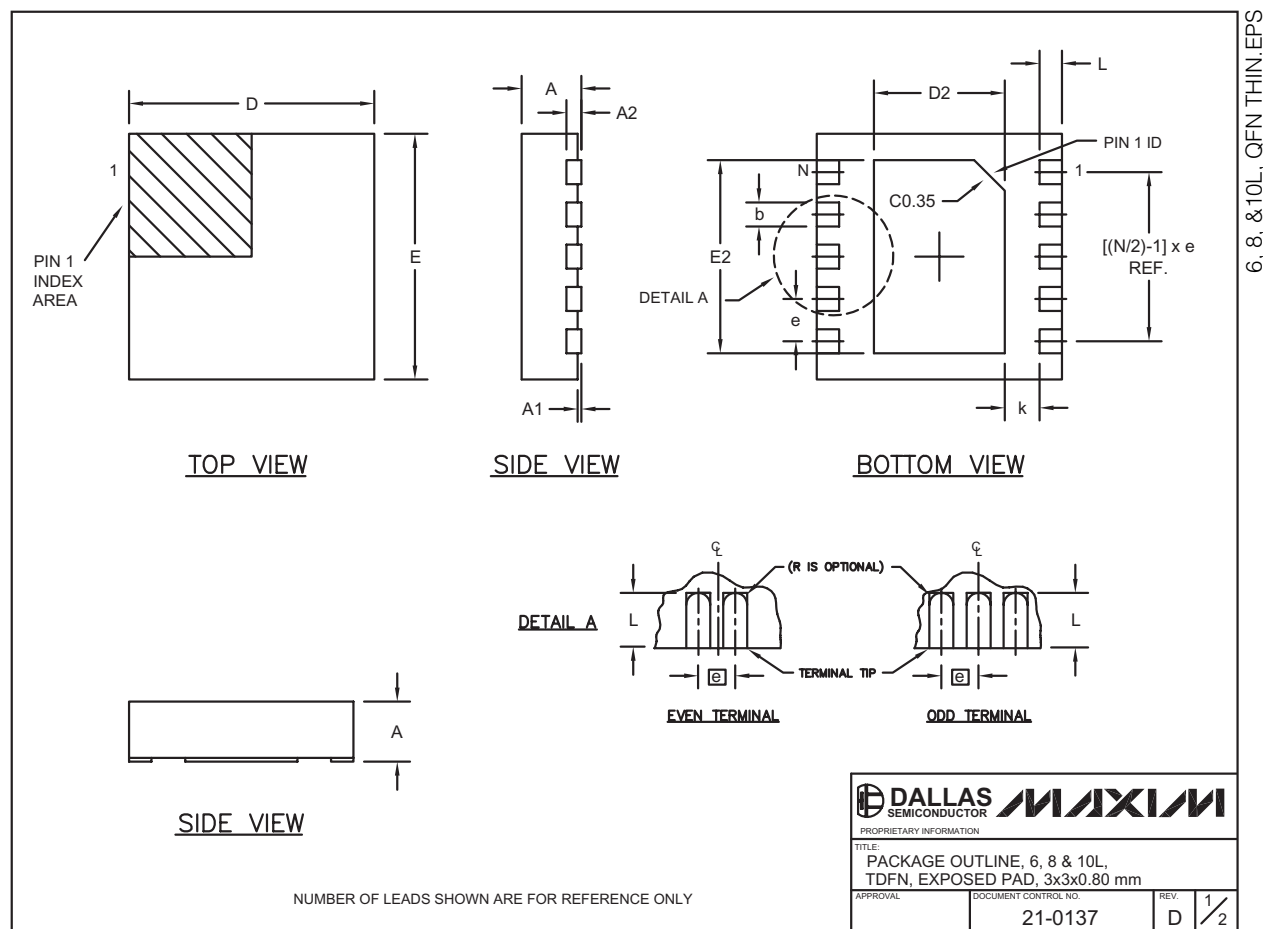
1. D&E DO NOT INCLUDE MOLD FLASH.
2. MOLD FLASH OR PROTRUSIONS NOT TO EXCEED 0.15mm (.006").
3. LEADS TO BE COPLANAR WITHIN 0.10mm (.004").
4. CONTROLLING DIMENSION: MILLIMETERS.
5. MEETS JEDEC MS012.
6. N = NUMBER OF PINS.

|                                                                                                                      |                                     |                                                                                       |     |
|----------------------------------------------------------------------------------------------------------------------|-------------------------------------|---------------------------------------------------------------------------------------|-----|
|  <b>DALLAS</b><br>SEMICONDUCTOR |                                     |  |     |
| PROPRIETARY INFORMATION                                                                                              |                                     |                                                                                       |     |
| TITLE:<br><br>PACKAGE OUTLINE, .150" SOIC                                                                            |                                     |                                                                                       |     |
| APPROVAL                                                                                                             | DOCUMENT CONTROL NO.<br><br>21-0041 | REV.<br><br>B                                                                         | 1/1 |

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)



6, 8, & 10L, QFN THIN.EPS

# Single/Dual/Quad, 28MHz, Low-Noise, Low-Voltage, Precision Op Amps

## Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to [www.maxim-ic.com/packages](http://www.maxim-ic.com/packages).)

MAX410/MAX412/MAX414

| COMMON DIMENSIONS |           |      |
|-------------------|-----------|------|
| SYMBOL            | MIN.      | MAX. |
| A                 | 0.70      | 0.80 |
| D                 | 2.90      | 3.10 |
| E                 | 2.90      | 3.10 |
| A1                | 0.00      | 0.05 |
| L                 | 0.20      | 0.40 |
| k                 | 0.25 MIN. |      |
| A2                | 0.20 REF. |      |

| PACKAGE VARIATIONS |    |           |           |          |                |           |               |
|--------------------|----|-----------|-----------|----------|----------------|-----------|---------------|
| PKG. CODE          | N  | D2        | E2        | e        | JEDEC SPEC     | b         | [(N/2)-1] x e |
| T633-1             | 6  | 1.50-0.10 | 2.30-0.10 | 0.95 BSC | MO229 / WEEA   | 0.40-0.05 | 1.90 REF      |
| T833-1             | 8  | 1.50-0.10 | 2.30-0.10 | 0.65 BSC | MO229 / WEEC   | 0.30-0.05 | 1.95 REF      |
| T1033-1            | 10 | 1.50-0.10 | 2.30-0.10 | 0.50 BSC | MO229 / WEED-3 | 0.25-0.05 | 2.00 REF      |

### NOTES:

1. ALL DIMENSIONS ARE IN mm. ANGLES IN DEGREES.
2. COPLANARITY SHALL NOT EXCEED 0.08 mm.
3. WARPAGE SHALL NOT EXCEED 0.10 mm.
4. PACKAGE LENGTH/PACKAGE WIDTH ARE CONSIDERED AS SPECIAL CHARACTERISTIC(S).
5. DRAWING CONFORMS TO JEDEC MO229, EXCEPT DIMENSIONS "D2" AND "E2".
6. "N" IS THE TOTAL NUMBER OF LEADS.

|                                                                                         |                                                |
|-----------------------------------------------------------------------------------------|------------------------------------------------|
|    |                                                |
| <small>PROPRIETARY INFORMATION</small>                                                  |                                                |
| <small>TITLE:</small><br>PACKAGE OUTLINE, 6, 8 & 10L,<br>TDFN, EXPOSED PAD, 3x3x0.80 mm |                                                |
| <small>APPROVAL</small>                                                                 | <small>DOCUMENT CONTROL NO.</small><br>21-0137 |
| <small>REV.</small><br>D                                                                | <small>2/2</small>                             |

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